Anderson-type model for a molecule adsorbed on a metal surface

Mahn-Soo Choi and C. Bruder

Departement Physik und Astronomie, Universität Basel, Klingelbergstrasse 82, CH-4056 Basel, Switzerland

```
(received; accepted)
```

PACS. 73.40Gk – Tunneling.

PACS. 85.65+h - Molecular electronic devices.

PACS. 61.16Ch – Scanning probe microscopy.

Abstract. – We investigate a modified Anderson model to study the local density of states (LDOS) of a molecular wire adsorbed on a metal. Using a self-consistent mean-field type approach we find an exponential decay of the LDOS along the molecule. A repulsive on-site interaction on the molecule suppresses the tunneling and decreases the characteristic decay length.

Introduction. — In the last decade, a lot of progress has been made in the theoretical and experimental investigation of nanostructures like quantum dots and quantum wires [1]. These structures are produced by lithography. Using this very flexible technology, a large variety of different structures with different geometries has been made. Simple dots, multiple dots, dot arrays and the corresponding leads have been realized both using metals and semiconductors. A disadvantage of lithographic methods is the presence of fluctuations in shape and size of these structures; they are unavoidable because of errors in writing the mask and because of the stochastic nature of the etching process.

The idea to use molecules or supramolecular structures as quantum wires and quantum dots has been around for quite a while, see Ref. [2] for an early suggestion of a molecular rectifier and Refs. [3, 4] for recent reviews. Powerful chemical synthesis methods are available that allow the production of atomic and molecular clusters with linear dimensions of up to 5 nm, i.e., they are approaching the lowest linear dimensions of nanostructures produced by lithography. It is a fascinating idea that such clusters which would have custom-made electronic properties could be included in nanostructures and replace, say, a quantum dot. Different copies of these systems would be identical in structure and properties (e.g., there is no difference in the composition of different C_{60} molecules). First steps in the direction of this 'bottom-up approach' are under way in a number of labs around the world. Scanning probe techniques have been used to arrange atoms on a substrate in arbitrary ways [5, 6]. A particularly impressive example is the 'quantum corral' [7], a circularly shaped structure of Fe atoms on a Cu(111) surface that may be considered a precursor of a device. Carbon

2 EUROPHYSICS LETTERS

nanotubes have been contacted and proven to exhibit Coulomb-blockade behavior [8, 9]. A new kind of transistor whose central element is a C_{60} molecule has been proposed [10]. The theory of conduction through molecular wires has been studied by a number of groups (see, e.g., Refs. [11, 12, 13, 14, 15]). Also, the thermal conduction through molecular wires has been investigated [16]. Recently, the coupling of a molecule to a metal has been studied both experimentally and theoretically [17, 18].

A central problem facing the use of molecules as electronic devices is the question of how to contact them in a reproducible way. An interesting answer to this question was given in a recent experiment [19] in which a custom-designed "lander" molecule [20] was adsorbed on a (111) copper surface. The molecules can be thought of as consisting of an aromatic platform and four spacer "legs". The spacer legs keep the main board at such a distance from the metal surface that the aromatic part is electronically decoupled from the surface.

The molecules self-assembled perpendicularly to a step on the surface, thereby forming a contact between the metal and the aromatic board (the length of the legs was chosen to be comparable to the step height). A scanning-tunneling microscope (STM) was used to scan along the surface and the molecule, and it was found that the tunneling conductance decayed in an exponential way along the molecule.

In this paper, we would like to study a (relatively) simple model for the molecule at the metal step. In contrast to the quantum-chemical calculations provided in [19] that take into account the precise structure of the lander molecule, we propose to use a modified Anderson model to describe this situation. The 'impurity' of the new model is spatially extended, i.e., contains internal degrees of freedom not present in the standard Anderson model. The aim will be to calculate the local density of states of an extended structure (the molecule) using a Green's function method. The molecule will be approximated by a (finite) one- or two-dimensional tight-binding lattice with a Hubbard-like interaction. Our goal is to gain a qualitative understanding of the physical problem and its phenomenology (as opposed to quantum-chemical calculations for specific molecules) to be able to propose and analyze more complicated (e.g., multiply-connected) structures in the future.

Model. – The system we have in mind is shown in Fig. 1. Our model is defined by a Hamiltonian that consists of three parts, $H = H_c + H_d + H_T$. The metal to which the molecular wire is attached is described by non-interacting electrons in a conduction band

$$H_c = \sum_{\mathbf{k}\sigma} \epsilon_{\mathbf{k}} c_{\mathbf{k}\sigma}^{\dagger} c_{\mathbf{k}\sigma} , \qquad (1)$$

where \mathbf{k} and $\sigma = \uparrow, \downarrow$ denote electron wave vectors and spins, respectively. The single-electron energy $\epsilon_{\mathbf{k}}$ is measured with respect to the Fermi energy ($\epsilon_F = 0$). The molecular wire is assumed to be a one-dimensional lattice of L atomic sites and is described within the Hubbard model

$$H_d = \sum_{i,j=1}^{L} t_{ij} d_{i\sigma}^{\dagger} d_{j\sigma} + U \sum_{j=1}^{L} n_{j\uparrow} n_{j\downarrow} . \tag{2}$$

The parameters that enter here are the on-site electron-electron interaction U and the matrix elements $t_{ij} = \epsilon_d \delta_{ij} - t \, \delta_{i,j\pm 1}$, where ϵ_d is the on-site energy of the single-particle level at each site and t is the hopping element between nearest neighbors. The coupling of the wire to the metal is assumed to be small so that we can describe it by the tunneling amplitude $V_{\mathbf{k}}$ of the electron in the state (\mathbf{k}, σ) to the first site j = 1:

$$H_T = -\sum_{\mathbf{k}\sigma} \left(V_{\mathbf{k}} c_{\mathbf{k}\sigma}^{\dagger} d_{1\sigma} + h.c. \right) . \tag{3}$$

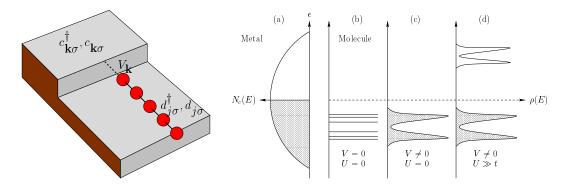


Fig. 1. – Left part: schematic view of the system. We describe the molecule by a tight-binding model, i.e., a discrete lattice of atomic sites. The coupling of the molecule to a metal consisting of non-interacting electrons in a conduction band is assumed to be small and characterized by the tunneling amplitude $V_{\mathbf{k}}$. Right part: sketch of the energy spectrum of the model. (a) unperturbed density of states $N_c(E)$ of the metal. (b) - (d) density of states $\rho(E)$ at a typical molecular site. (b) Isolated molecule ($V_{\mathbf{k}}=0$) without electron-electron interaction (U=0). (c) Molecule without interaction coupled to the metal. The coupling broadens the discrete molecular levels. (d) Molecule in the presence of strong electron-electron interaction ($U\gg t$) coupled to the metal. In the half-filled case (one electron per site), the interaction will lead to the formation of an upper Hubbard band.

The model defined by H is a generalization of the Anderson impurity model: for L=1, the molecule reduces to a localized level, and (3) is the hybridization term of the Anderson impurity model.

The qualitative nature of the spectrum of the system is shown in the right part of Fig. 1. We characterize the metal by a model density of states $N_c(E)$ to be discussed below and shown schematically in (a). If the molecule is not coupled to the metal, V = 0, its spectrum consists of discrete levels as shown in (b). Coupling the molecule to the metal broadens the spectral lines as shown in (c). If we assume a filling of one electron per site, the presence of strong on-site interactions leads to the formation of a Mott-Hubbard gap as shown in (d).

We will use the imaginary-time path-integral formalism at finite temperature $k_B T \equiv 1/\beta$ (see, e.g., Ref. [21]). In this formalism, the Euclidean action is given by

$$S^{E} = \int_{0}^{\beta} d\tau \left(\sum_{\mathbf{k}\sigma} c_{\mathbf{k}\sigma}^{\dagger} \partial_{\tau} c_{\mathbf{k}\sigma} + \sum_{j\sigma} d_{j\sigma}^{\dagger} \partial_{\tau} d_{j\sigma} + H \right) , \qquad (4)$$

and we want to calculate the thermal Green's function

$$\mathcal{G}(j\sigma, k\sigma'; \tau) = -\left\langle T_{\tau} d_{j\sigma}^{\dagger}(0) d_{k\sigma'}(\tau) \right\rangle \tag{5}$$

and its Fourier transform defined by $\mathcal{G}(j\sigma, k\sigma'; i\omega_n) = \int_0^\beta d\tau \ e^{i\omega_n\tau} \mathcal{G}(j\sigma, k\sigma'; \tau)$, where $\omega_n \equiv (2n+1)\pi/\beta$ with n integer are the Matsubara frequencies.

First, we consider the non-interacting case, U=0. In this case, the Euclidean action (4) is quadratic both in $c_{\mathbf{k}\sigma}(c_{\mathbf{k}\sigma}^{\dagger})$ and $d_{j\sigma}(d_{j\sigma}^{\dagger})$, and it follows that $\mathcal{G}(j\sigma, k\sigma'; i\omega_n) = \delta_{\sigma\sigma'}\mathcal{G}(j, k; i\omega_n)$,

$$\mathcal{G}^{-1}(j,k;i\omega_n) = \mathcal{G}_0^{-1}(j,k;i\omega_n) - \Sigma_c(j,k;i\omega_n) , \qquad (6)$$

or more explicitly

$$\mathcal{G}(i,j) = \mathcal{G}_0(i,j) + \frac{\mathcal{G}_0(i,0)\Sigma_c(0,0)\mathcal{G}_0(0,j)}{1 - \mathcal{G}_0(0,0)\Sigma_c(0,0)}.$$
 (7)

4 EUROPHYSICS LETTERS

The unperturbed (non-interacting, isolated) Green's function is given by

$$\mathcal{G}_0^{-1}(j,k;i\omega_n) = i\omega_n - t_{jk} \ . \tag{8}$$

In Eqs. (6) and (7), the coupling to the metal manifests its effect on the wire through the self-energy

$$\Sigma_c(j, k; i\omega_n) = \delta_{j1}\delta_{k1} \int_{-\infty}^{\infty} \frac{d\epsilon}{2\pi} \frac{\Gamma(\epsilon)}{i\omega_n - \epsilon} . \tag{9}$$

The effect of the metal on the molecular wire is given by the function

$$\Gamma(E) \equiv -2\sum_{\mathbf{k}} |V_{\mathbf{k}}|^2 \text{Im} G_c^R(\mathbf{k}, E) , \qquad (10)$$

where $G_c^R(\mathbf{k}, E)$ is the retarded Green's function for the (unperturbed) metal. In the simplest case in which the energy-dependence of the tunneling amplitude $V_{\mathbf{k}}$ is not too large, $V_{\mathbf{k}} \approx V$, (10) can be further reduced to an expression directly proportional to the density of states in the metal $N_c(E)$: $\Gamma(E) = 2\pi V^2 N_c(E)$.

The local density of states (LDOS) at the jth site is then given by the analytic continuation of the thermal Green's function.

$$\rho(j, E) = -\frac{2}{\pi} \operatorname{Im} \mathcal{G}(j, j; i\omega_n \to E + i0^+) . \tag{11}$$

The factor 2 accounts for the contributions from the two spin components.

We now turn to the opposite limit in which the electron-electron interaction on the molecule is very strong; $U \gg t$ [22]. In this case, exact solutions are only available in special cases; the isolated molecule $(V_{\mathbf{k}} = 0)$, i.e, the usual Hubbard model [23] and the single-site molecule (L = 1), i.e., the usual Anderson impurity model [24]. There are many approximation methods for the Hubbard model or the Anderson model (see Ref. [25] for a recent review), and we will adopt a self-consistent mean-field approximation [21].

We start with the strong-U limit of H_d in (2), i.e., the t-J Hamiltonian [26]

$$H_d \simeq \sum_{ij} t_{ij} d_{i\sigma}^{\dagger} d_{j\sigma} - \frac{1}{U} \sum_{ijk} t_{ij} (d_{i\uparrow}^{\dagger} d_{j\downarrow}^{\dagger} - d_{i\downarrow}^{\dagger} d_{j\uparrow}^{\dagger}) t_{jk} (d_{j\downarrow} d_{k\uparrow} - d_{j\uparrow} d_{k\downarrow})$$
 (12)

within the reduced Hilbert space without doubly occupied sites. The second term in (12) can be made quadratic in $d_{j\sigma}(d_{j\sigma}^{\dagger})$ by means of the Hubbard-Stratonovich transformation introducing the auxiliary field Δ_j to get the molecular part (corresponding to H_d) in the Euclidean action (4)

$$S_d^E = S_\Delta^E + \int_0^\beta d\tau \sum_{ij} \hat{d}_i^{\dagger} \left[\delta_{ij} \partial_\tau + t_{ij} \hat{\tau}_3 - \widehat{\Delta}_{ij} \right] \hat{d}_j , \qquad (13)$$

where τ_3 is the Pauli matrix and $S_{\Delta}^E = \int_0^{\beta} d\tau \ U \sum_j |\Delta_j|^2$. In Eq. (13), we have introduced a two-component spinor representation

$$\hat{d}_{j} \equiv \begin{bmatrix} d_{j\uparrow} \\ d_{j\downarrow}^{\dagger} \end{bmatrix}, \quad \hat{\Delta}_{ij} \equiv t_{ij} \begin{bmatrix} 0 & \Delta_{i} + \Delta_{j} \\ \Delta_{i}^{*} + \Delta_{j}^{*} & 0 \end{bmatrix}.$$
 (14)

In this representation, the Green's function in Eq. (5) also has a matrix form $\widehat{\mathcal{G}}(i,j;\tau) = -\left\langle T_{\tau}\widehat{d}_{i}(0)\widehat{d}_{j}^{\dagger}(\tau)\right\rangle$. After integrating out the fields $c_{\mathbf{k}\sigma}$ and $c_{\mathbf{k}\sigma}^{\dagger}$, the Euclidean action can be

written as

$$S^{E} = S_{\Delta}^{E} - \iint_{0}^{\beta} d\tau d\tau' \, \hat{d}_{i}^{\dagger}(\tau) \widehat{\mathcal{G}}^{-1}(i, j; \tau - \tau') \hat{d}_{j}(\tau') \tag{15}$$

where the Green's function \mathcal{G} is given by the Dyson equation

$$\widehat{\mathcal{G}}^{-1}(j,k;i\omega_n) = \widehat{\mathcal{G}}_0^{-1}(j,k;i\omega_n) - \widehat{\Sigma}_c(j,k;i\omega_n) - \widehat{\Sigma}(j,k;i\omega_n) , \qquad (16)$$

with the new self-energy term $\widehat{\Sigma}(i,j;\tau) = -\delta(\tau)\widehat{\Delta}_{ij}(\tau)$. Here \mathcal{G}_0 in (8) and Σ_c in Eq. (9) have been extended to matrix form in a trivial way: $\widehat{\mathcal{G}}_0 = \mathcal{G}_0\widehat{\tau}_0$ and $\widehat{\Sigma}_c = \Sigma_c\widehat{\tau}_0$, where τ_0 is the identity matrix.

So far no approximation has been made and the formal expression for the Euclidean action in Eq. (15) is exact. The interaction effect is correctly incorporated through the self-energy term $\widehat{\Sigma}$ (whereas the effect of the metal is again manifested by $\widehat{\Sigma}_c$) as long as the integration over the field Δ_j is performed properly. At this point, we make our main approximation and neglect the fluctuations in the field Δ_j . We first assume a particular realization of the field Δ_j in the Dyson equation (16) and then determine Δ_j within the stationary-phase approximation. Iterating this procedure allows us to determine Δ_j and the Green's function self-consistently. Moreover, the self-consistency equation

$$\Delta_i = \frac{1}{U} \sum_j t_{ij} \left\langle d_{i\downarrow} d_{j\uparrow} - d_{i\uparrow} d_{j\downarrow} \right\rangle \tag{17}$$

corresponding to this procedure, gives us a physical interpretation of the field Δ_j : Δ_j measures the spin-singlet correlation between the jth site and its neighboring sites. It is clear that in the limit $U \to \infty$, $\Delta_j \approx 2t/U$ unless j is too close to the boundaries. Finally, the LDOS can be obtained from the diagonal components of the retarded Green's function $\hat{G}^R(j,k;E) = \widehat{\mathcal{G}}(j,k;i\omega_n \to E+i0^+)$:

$$\rho(j, E) = -\frac{1}{\pi} \text{Im} \left[\hat{G}_{11}^{R}(j, j; E) + \hat{G}_{22}^{R}(j, j; -E) \right] . \tag{18}$$

Results. – We will now report specific results on the LDOS of the molecular wire and discuss their physical implications. For the density of states (DOS) in the metal, we adopt the model functional form $N_c(E) = N_c(0)(1 - E^2/W_c^2)$. The parameters $N_c(0)$ and W_c specify the DOS at the Fermi energy and the width of the conduction band, respectively. The self-energy contribution (9) from the coupling to the metal is then given by

$$\Sigma_c(j,k;E) = \delta_{j1}\delta_{k1} V^2 \left[\alpha_c(E) - i\pi N_c(E)\right]$$
(19)

with $\alpha_c(E)$ defined by

$$\alpha_c(E) = N_c(0) \left[\frac{2E}{W_c} + \left(1 - \frac{E^2}{W_c^2} \right) \ln \left| \frac{E/W_c + 1}{E/W_c - 1} \right| \right] . \tag{20}$$

All results shown in this work will be generated using the values $\epsilon_d = -4t$, V = 0.1t, $W_c = 40t$, and $N_c(0) = 10/t$. The other parameters will be specified as needed. We also remark that we only investigate the lower band, i.e., the band below the Mott-Hubbard gap, in the interacting case.

In Fig. 2 we plot typical LDOS curves at three different sites (j = 1, 3, and 5) on a molecule with size L = 10 and on-site interaction U = 10t. The structures get sharper as U increases [27] because tunneling is blocked, see the discussion below. At a given site, the LDOS decays rapidly outside the band.

6 EUROPHYSICS LETTERS

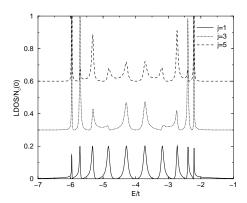


Fig. 2. – Local density of states at site j for L = 10 and U = 10t. Solid line: j = 1, dotted line: j = 3 (shifted upwards by 0.3), dashed line: j = 5 (shifted upwards by 0.6).

Figure 3 shows the spatial dependence of the LDOS along molecules with sizes L=10 and 20, respectively, both for the non-interacting (open circle) and interacting (solid circle) case. The LDOS has been calculated at the fixed energy E=-2t, slightly above the upper edge of the band (remember that at the parameter values chosen below Eq. (20), E = -2t is the upper edge of the band for an infinite tight-binding chain, i.e., H_d with $L = \infty$ and U = 0 in Eq. (2)). The LDOS decays exponentially with distance from the metal-molecule contact, except for the region close to the boundaries. This reproduces the exponential decay of the STM tunneling conductance in Ref. [19]. It also agrees with the expectation that the electron wave function induced by the metal to the molecule should decay in an exponential way. Another interesting conclusion that can be drawn from Fig. 3 is the influence of the interaction on the suppression of the LDOS. The characteristic decay length decreases with the interaction U. This can be interpreted by saying that the strong repulsion by the electrons sitting on (singly-occupied) sites tends to block tunneling events from the metal to the molecule. This effectively leads to the suppression of the "hybridization" term H_T , Eq. (3). The suppression of the LDOS by interaction effects does not depend on the choice E=-2t, however, the spatial scale would be different for different positions of the molecular level. The influence of repulsive interactions was also studied in [28], where it is shown that the suppression is lower for repulsive interactions than for a dimerization leading to the same value of the gap.

In conclusion, we have calculated the local density of states of a molecule adsorbed to a metal surface using a new Anderson-type model. The LDOS decays along the molecule in an exponential way (like in the experiment [19]) and is suppressed by a local interaction on the molecule. Our formalism provides a qualitative understanding of this and similar experiments. It is able to include local interaction effects and can be used to treat more complicated geometries that will be investigated in future experiments.

We would like to acknowledge discussions with T. Jung and A. Baratoff and thank J. Gimzewski for providing a preprint of Ref. [19].

REFERENCES

[1] Mesoscopic Electron Transport, edited by L. L. Sohn, L. P. Kouwenhoven, and G. Schön (Kluwer, Dordrecht, 1997).

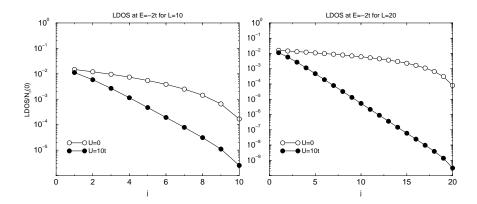


Fig. 3. – Spatial dependence of the local density of states along the molecule. Empty symbols: non-interacting case. Full symbols: interacting case, U = 10t. Interaction effects on the molecule depress the influence of the metals on the density of states on sites that are far away.

- [2] A. Aviram and M. A. Ratner, Chem. Phys. Lett. 29, 277 (1974).
- [3] Introduction to Molecular Electronics, edited by M. C. Petty, M. R. Bryce, and D. Bloor (Oxford University Press, Oxford, 1995).
- [4] Molecular Electronics: Science and Technology, edited by A. Aviram and M. Ratner, Ann. N.Y. Acad. Sci. 852 (1998).
- [5] D. M. Eigler and E. K. Schweizer, Nature **344**, 524 (1990).
- [6] I.-W. Lyo and P. Avouris, Science **253**, 173 (1991).
- [7] M. F. Crommie, C. P. Lutz, and D. M. Eigler, Science **262**, 218 (1993).
- [8] S. J. Tans et al., Nature 386, 474 (1997); S. J. Tans, R. M. Verschueren, and C. Dekker, Nature 393, 49 (1998).
- [9] A. Bachtold et al., Appl. Phys. Lett. 73, 274 (1998).
- [10] C. Joachim, J. K. Gimzewski, and H. Tang, Phys. Rev. B 58, 16407 (1998).
- [11] V. Mujica, M. Kemp, and M. A. Ratner, J. Chem. Phys. **101**, 6849 (1994); 6856 (1994).
- [12] C. Joachim and J. F. Vinuesa, Europhys. Lett. 33, 635 (1996).
- [13] M. Magoga and C. Joachim, Phys. Rev. B 56, 4722 (1997); Phys. Rev. B 57, 1820 (1998).
- [14] S. Datta and W. Tian, Phys. Rev. B 55, R1914 (1997).
- [15] E. G. Emberly and G. Kirczenow, Phys. Rev. B 58, 10911 (1998); see also cond-mat/9908392.
- [16] A. Buldum, D. M. Leitner, and S. Ciraci, Europhys. Lett. 47, 208 (1999); A. Buldum, S. Ciraci, and C. Y. Fong, cond-mat/9908204.
- [17] C. Kergueris et al., Phys. Rev. B 59, 12505 (1999).
- [18] Y. Xue and S. Datta, cond-mat/9908073.
- [19] V. J. Langlais et al., Phys. Rev. Lett. 83, 2809 (1999).
- [20] A. Gourdon and H. Tang, Ann. N.Y. Acad. Sci. 852, 219 (1998).
- [21] J. W. Negele and H. Orland, Quantum Many-Particle Systems (Addison-Wesley, Redwood, 1988); E. Fradkin, Field Theories of Condensed Matter Systems (Addison-Wesley, New York, 1991).
- [22] In practice, the band gap is due to both correlation and dimerization effects. In this work, we concentration on the correlation effects.
- [23] E. H. Lieb and F. Y. Wu, Phys. Rev. Lett. 20, 1445 (1968).
- [24] P. B. Wiegmann, Phys. Lett. A 31, 163 (1981); N. Kawakami and A. Okiji, Phys. Lett. A 86, 483 (1981).
- [25] A. Georges, G. Kotliar, W. Krauth, and M. J. Rozenberg, Rev. Mod. Phys. 68, 13 (1996).
- [26] A. Auerbach, Interacting Electrons and Quantum Magnetism (Springer-Verlag, Heidelberg, 1994).
- [27] W. F. Brinkman and T. M. Rice, Phys. Rev. B 2, 1324 (1970).
- [28] J. Favand and F. Mila, Eur. Phys. J. B 2, 293 (1998).